

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

## **IRLR7843, IIRLR7843**

#### FEATURES

- Static drain-source on-resistance: Ros(on)≤3.3mΩ
- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRITION

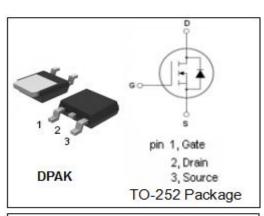
• High Frequency Synchronous Buck Converters For Computer Processor Power

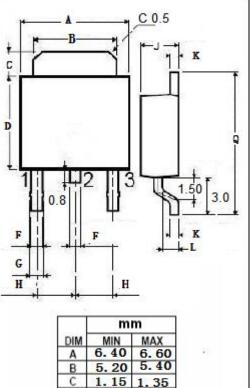
#### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>DSS</sub>	Drain-Source Voltage	30	V			
V <sub>GS</sub>	Gate-Source Voltage	±20	V			
ID	Drain Current-Continuous	161	А			
I <sub>DM</sub>	Drain Current-Single Pulsed	620	А			
PD	Total Dissipation @Tc=25°C 140		W			
Tj	Max. Operating Junction Temperature	175	°C			
T <sub>stg</sub>	Storage Temperature	-55~175	°C			

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT	
Rth(j-c)	Channel-to-case thermal resistance	1.05	°C/W	
Rth(j-a)	Rth(j-a) Channel-to-ambient thermal resistance		°C <b>/W</b>	





5.70 6. 0.65 0.

2.10

2.10

0.40 0.90 9.90 75

2 50

10

2.40

### isc website: www.iscsemi.cn

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#### ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =250 μ A	30			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	VDS=VGS; I <sub>D</sub> =250 µ A	1.4		2.3	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =15A			3.3	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =24V; V <sub>GS</sub> = 0V			1	μA
V <sub>SD</sub>	Diode forward voltage	I <sub>s</sub> =12A, V <sub>GS</sub> = 0V			1.0	V

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